

Roll No. .... [ Total No. of Pages : 7

**EC-1848**

**B. Tech. (First Semester)**

**EXAMINATION, 2020**

**ELECTRONICS ENGINEERING**

*Time : Three Hours*

*Maximum Marks : 100*

**Note :** Attempt questions from both Sections as directed.

**Section—A**

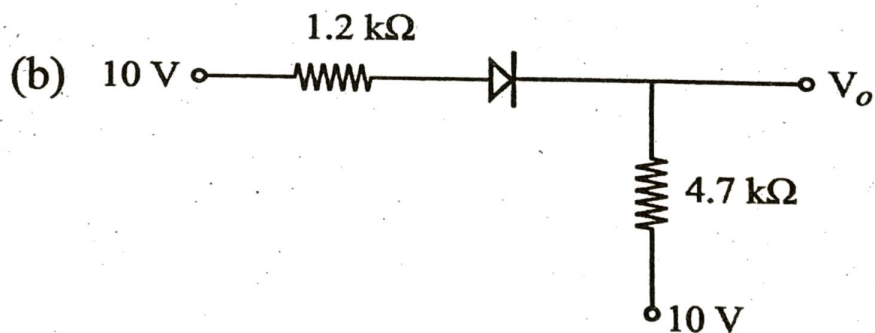
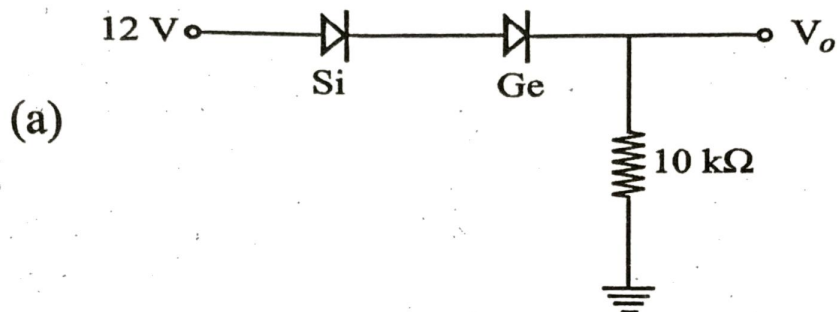
**(Short Answer Type Questions)**

**Note :** Attempt any *ten* questions. Each question carries 4 marks.  $10 \times 4 = 40$

1. What is meant by exceptor and donor impurities ?
2. Describe the static and dynamic resistance of diode.

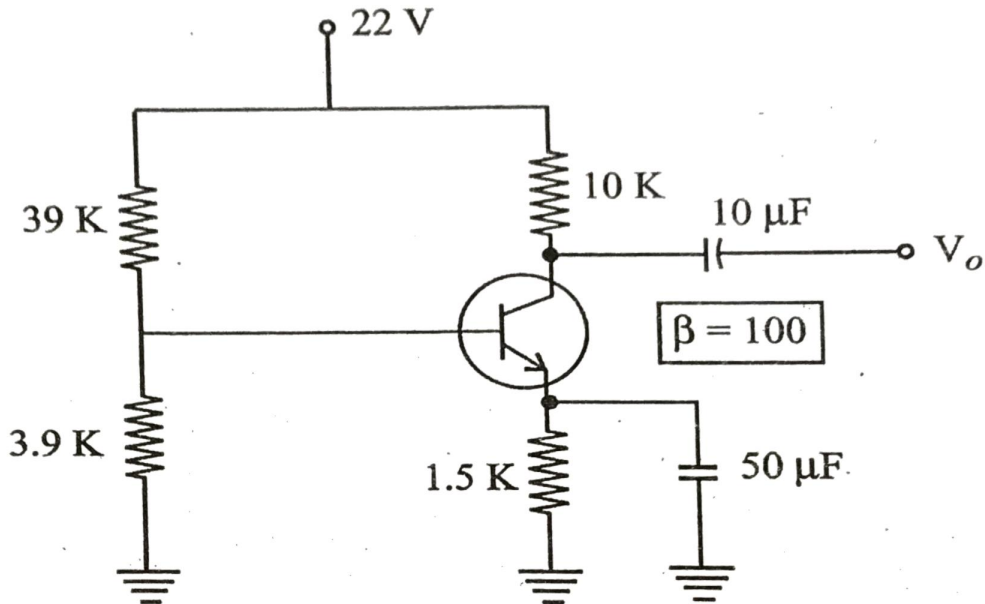
**P. T. O.**

3. Draw the V-I characteristics of diode and explain it.
4. Determine the level of  $V_o$  for each network of given figure :



5. Explain the working of full wave bridge rectifier.
6. What is the significance of Q point in transistor ? Explain with neat diagram.

7. Determine the d.c. bias voltage  $V_{CE}$  and current  $I_C$  for the voltage divider configuration of given Fig. :



8. Find out the expression for Ripple factor.
9. (i) Convert the decimal number 53.62 into an equivalent binary number.
- (ii) Convert  $(444.456)_{10}$  to an octal number.
10. Explain voltage follower or unit gain configuration of Op-Amp.
11. Explain the concept of virtual ground in Op-Amp. circuits.

13. Determine the following for the network of given Fig. :

(a)  $V_{GS}$

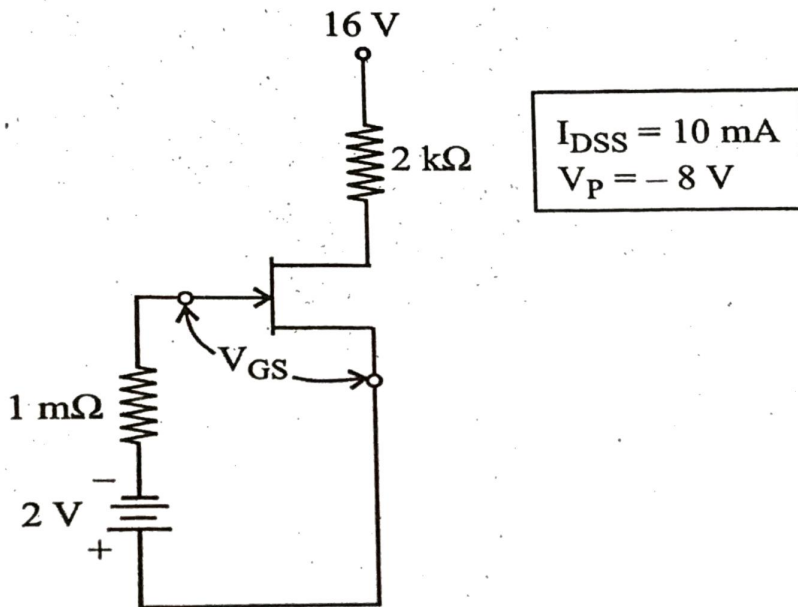
(b)  $I_D$

(c)  $V_{DS}$

(d)  $V_D$

(e)  $V_G$

(f)  $V_S$



13. With the help of neat diagram, explain pinch-off condition in FET.

14. Prove that :

(i)  $A + BC = (A + B)(A + C)$

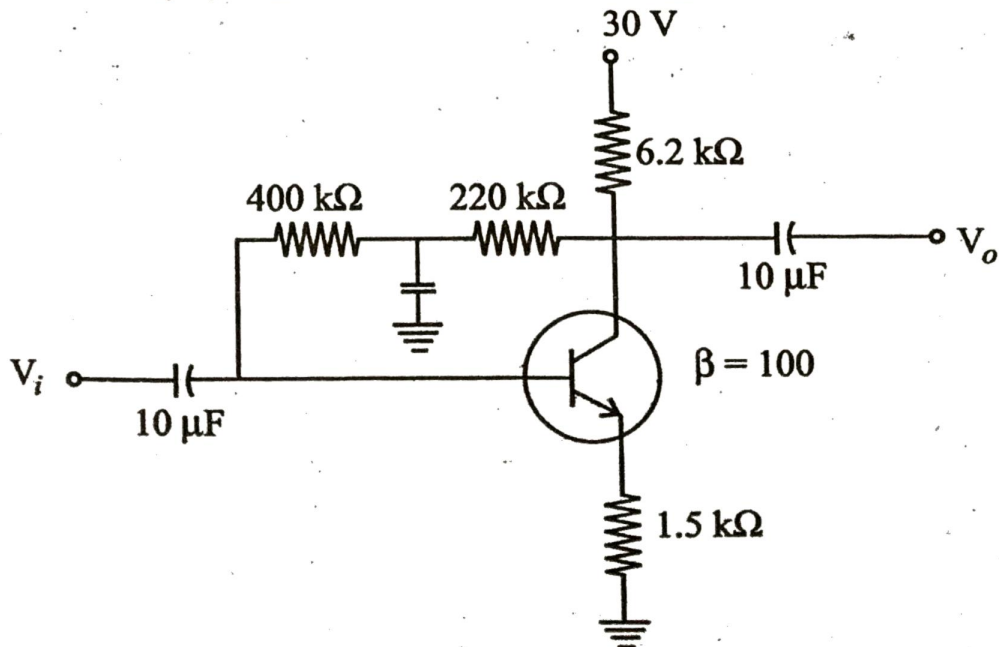
(ii)  $A \vee (A + B) = A$

## Section—B

## (Long Answer Type Questions)

**Note :** Attempt any *three* questions. Each question carries 20 marks.  $3 \times 20 = 60$

1. (a) What do you understand by clipper and clamper circuits ? Explain with suitable diagram.
- (b) Explain the working of P-N junction diode.
2. (a) For a voltage feedback network shown in Fig. given below, determine :
  - (i)  $I_C$
  - (ii)  $V_C$
  - (iii)  $V_E$
  - (iv)  $V_{CE}$





- (b) With the help of a neat diagram, explain potential divider biasing. Also find out the expression for base current  $I_b$  and output voltage  $V_{CE}$ .
3. (a) With the help of a neat diagram, explain construction of D-MOSFET. Also explain its working.
- (b) With the help of suitable diagram, explain the working of N-channel FET.
4. (a) With the help of block diagram, explain digital multimeter (DMM).
- (b) With the help of a block diagram, explain the working of CRO.
5. (a) What do you understand by Op-Amp. ? Explain, how Op-Amp. performs addition operation.
- (b) Draw the circuit diagram of an Op-Amp. integrator and show that output voltage is an integration of input voltage.

6. Write short notes on the following :

- (a) Universal gates
- (b) De Morgan's theorems
- (c) Minimization techniques
- (d) Ramp type DVM